

DATA SHEET

74LV164

8-bit serial-in/parallel-out shift register

Product specification
Supersedes data of 1997 Mar 28
IC24 Data Handbook

1998 May 07

8-bit serial-in/parallel-out shift register

74LV164

FEATURES

- Wide operating voltage: 1.0 to 5.5V
- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between $V_{CC} = 2.7V$ and $V_{CC} = 3.6V$
- Typical V_{OLP} (output ground bounce) $< 0.8V$ @ $V_{CC} = 3.3V$, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) $> 2V$ @ $V_{CC} = 3.3V$, $T_{amb} = 25^{\circ}C$
- Gated serial data inputs
- Asynchronous master reset
- Output capability: standard
- I_{CC} category: MSI

DESCRIPTION

The 74LV164 is a low-voltage Si-gate CMOS device and is pin and function compatible with the 74HC/HCT164.

The 74LV164 is an 8-bit edge-triggered shift register with serial data entry and an output from each of the eight stages. Data is entered serially through one of two inputs (D_{sa} or D_{sb}); either input can be used as an active HIGH enable for data entry through the other input. Both inputs must be connected together or an unused input must be tied HIGH.

Data shifts one place to the right on each LOW-to-HIGH transition of the clock (CP) input and enters into Q_0 , which is the logical AND of the two data inputs (D_{sa} , D_{sb}) that existed one set-up time prior to the rising clock edge.

A LOW on the master reset (MR) input overrides all other inputs and clears the register asynchronously, forcing all outputs LOW.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \leq 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay CP to Q_n MR to Q_n	$C_L = 15pF$ $V_{CC} = 3.3V$	12 12	ns
f_{max}	Maximum clock frequency		78	MHz
C_I	Input capacitance		3.5	pF
C_{PD}	Power dissipation capacitance per gate	$V_{CC} = 3.3V$ Notes 1 and 2	40	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.
2. The condition is $V_I = GND$ to V_{CC}

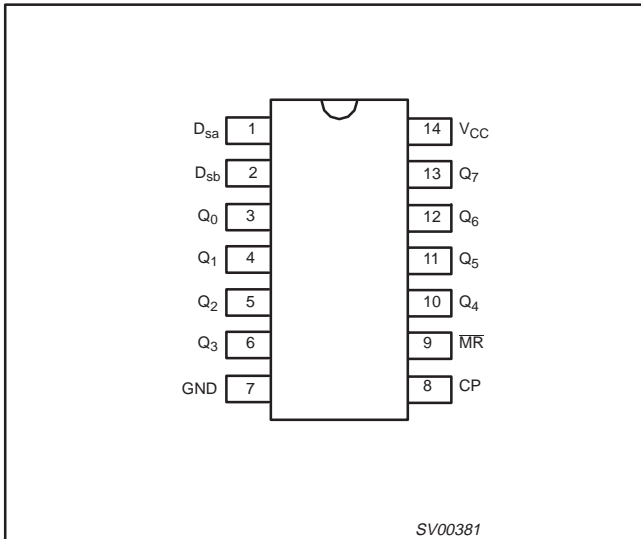
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40°C to +125°C	74LV164 N	74LV164 N	SOT27-1
14-Pin Plastic SO	-40°C to +125°C	74LV164 D	74LV164 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +125°C	74LV164 DB	74LV164 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV164 PW	74LV164PW DH	SOT402-1

8-bit serial-in/parallel-out shift register

74LV164

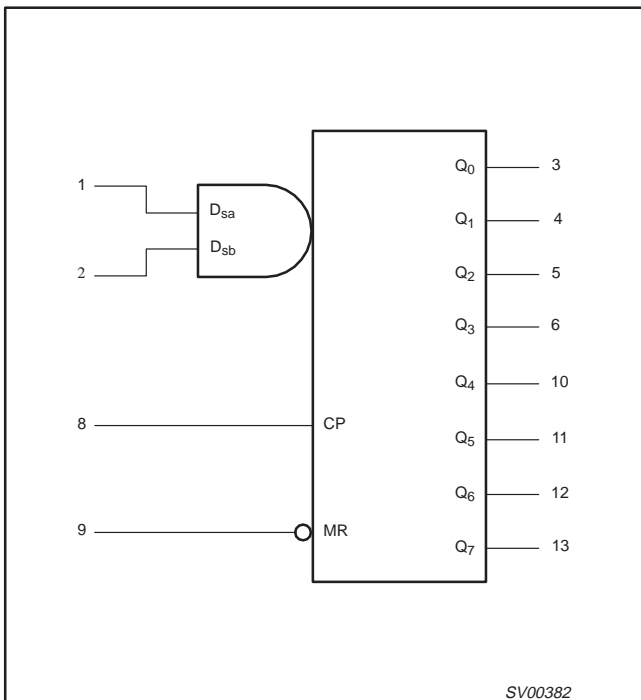
PIN CONFIGURATION



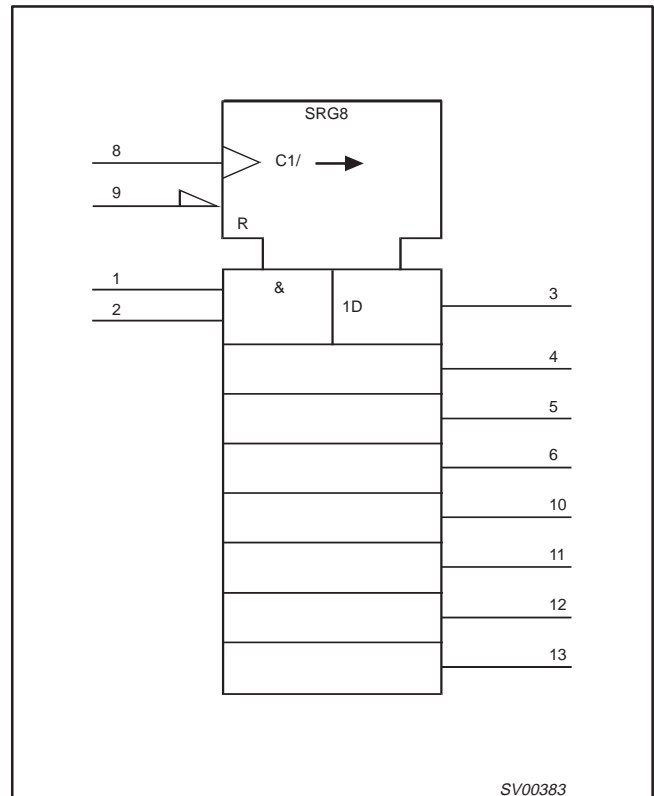
PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1,2	D _{sa} , D _{sb}	Data inputs
3, 4, 5, 6, 10, 11, 12, 13	Q ₀ to Q ₇	Outputs
7	GND	Ground (0V)
8	CP	Clock input (LOW-to-HIGH, edge-triggered)
9	$\overline{\text{MR}}$	Master reset input (active LOW)
14	V _{CC}	Positive supply voltage

LOGIC SYMBOL



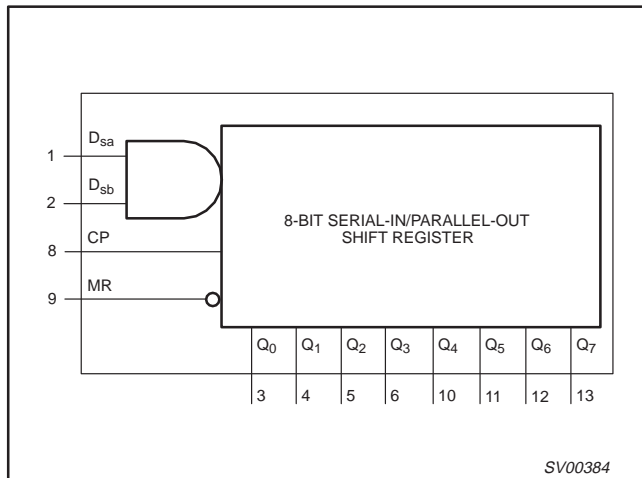
LOGIC SYMBOL (IEEE/IEC)



8-bit serial-in/parallel-out shift register

74LV164

FUNCTIONAL DIAGRAM



FUNCTION TABLE

OPERATING MODES	INPUTS				OUTPUTS	
	MR	CP	D _{sa}	D _{sb}	Q ₀	Q ₁ - Q ₇
Reset (clear)	L	X	x	x	L	L - L
Shift	H	↑	l	l	L	q ₀ - q ₆
	H	↑	l	h	L	q ₀ - q ₆
	H	↑	h	l	L	q ₀ - q ₆
	H	↑	h	h	H	q ₀ - q ₆

H = HIGH voltage level
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition
L = LOW voltage level
l = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition
q = Lower case letter indicates the state of referenced input one set-up time prior to the LOW-to-HIGH CP transition
↑ = LOW-to-HIGH clock transition

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134)
Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
±I _{IK}	DC input diode current	V _I < -0.5 or V _I > V _{CC} + 0.5V	20	mA
±I _{OK}	DC output diode current	V _O < -0.5 or V _O > V _{CC} + 0.5V	50	mA
±I _O	DC output source or sink current - standard outputs	-0.5V < V _O < V _{CC} + 0.5V	25	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with -standard outputs		50	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{TOT}	Power dissipation per package -plastic DIL -plastic mini-pack (SO) -plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
V _I	Input voltage		0	-	V _{CC}	V
V _O	Output voltage		0	-	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.0V to 2.0V V _{CC} = 2.0V to 2.7V V _{CC} = 2.7V to 3.6V V _{CC} = 3.6V to 5.5V	- - - -	- - - -	500 200 100 50	ns/V

NOTES:

- The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5V.

8-bit serial-in/parallel-out shift register

74LV164

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40°C to +85°C			-40°C to +125°C		
			MIN	TYP ¹	MAX	MIN	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2V	0.9			0.9		V
		V _{CC} = 2.0V	1.4			1.4		
		V _{CC} = 2.7 to 3.6V	2.0			2.0		
		V _{CC} = 4.5 to 5.5V	0.7*V _{CC}			0.7*V _{CC}		
V _{IL}	LOW level Input voltage	V _{CC} = 1.2V			0.3	0.3	V	
		V _{CC} = 2.0V			0.6	0.6		
		V _{CC} = 2.7 to 3.6V			0.8	0.8		
		V _{CC} = 4.5 to 5.5			0.3*V _{CC}	0.3*V _{CC}		
V _{OH}	HIGH level output voltage; all outputs	V _{CC} = 1.2V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA		1.2			V	
		V _{CC} = 2.0V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	1.8	2.0		1.8		
		V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	2.5	2.7		2.5		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	2.8	3.0		2.8		
		V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	4.3	4.5		4.3		
V _{OH}	HIGH level output voltage; STANDARD outputs	V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; -I _O = 6mA	2.40	2.82		2.20	V	
		V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; -I _O = 12mA	3.60	4.20		3.50		
V _{OL}	LOW level output voltage; all outputs	V _{CC} = 1.2V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0			V	
		V _{CC} = 2.0V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2	0.2		
		V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2	0.2		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2	0.2		
		V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2	0.2		
V _{OL}	LOW level output voltage; STANDARD outputs	V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 6mA		0.25	0.40	0.50	V	
		V _{CC} = 4.5V; V _I = V _{IH} or V _{IL} ; I _O = 12mA		0.35	0.55	0.65		
I _I	Input leakage current	V _{CC} = 5.5V; V _I = V _{CC} or GND			1.0	1.0	µA	
I _{CC}	Quiescent supply current; MSI	V _{CC} = 5.5V; V _I = V _{CC} or GND; I _O = 0			20.0	160	µA	
ΔI _{CC}	Additional quiescent supply current per input	V _{CC} = 2.7V to 3.6V; V _I = V _{CC} - 0.6V			500	850	µA	

NOTES:1. All typical values are measured at T_{amb} = 25°C.

8-bit serial-in/parallel-out shift register

74LV164

AC CHARACTERISTICS

GND = 0V; $t_r = t_f \leq 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 1\text{k}\Omega$

SYMBOL	PARAMETER	WAVEFORM	CONDITION	LIMITS -40 to +85 °C			LIMITS -40 to +125 °C		UNIT
				MIN	TYP ¹	MAX	MIN	MAX	
$t_{\text{PHL}}/t_{\text{PLH}}$	Propagation delay CP to Q_n	Figure 1	1.2	–	75	–	–	–	ns
			2.0	–	26	39	–	49	
			2.7	–	19	29	–	36	
			3.0 to 3.6	–	14 ²	23	–	29	
			4.5 to 5.5	–	12 ²	19	–	24	
t_{PHL}	Propagation delay MR to Q_n	Figure 2	1.2	–	75	–	–	–	ns
			2.0	–	26	39	–	49	
			2.7	–	19	29	–	36	
			3.0 to 3.6	–	14 ²	23	–	29	
			4.5 to 5.5	–	12 ²	19	–	24	
t_w	Clock pulse width HIGH to LOW	Figure 1	2.0	34	9	–	41	–	ns
			2.7	25	6	–	30	–	
			3.0 to 3.6	20	5 ²	–	24	–	
			4.5 to 5.5	13	4 ²	–	16	–	
t_w	Master reset pulse width; LOW	Figure 2	2.0	34	10	–	41	–	ns
			2.7	25	8	–	30	–	
			3.0 to 3.6	20	6 ²	–	24	–	
			4.5 to 5.5	13	5 ²	–	16	–	
t_{rem}	Removal time MR to CP	Figure 2	1.2	–	30	–	–	–	ns
			2.0	19	10	–	24	–	
			2.7	14	8	–	18	–	
			3.0 to 3.6	11	6 ²	–	14	–	
			4.5 to 5.5	8	5 ²	–	10	–	
t_{su}	Set-up time D_{sa} , D_{sb} to CP	Figure 3	1.2	–	15	–	–	–	ns
			2.0	22	5	–	26	–	
			2.7	16	4	–	19	–	
			3.0 to 3.6	13	3 ²	–	15	–	
			4.5 to 5.5	9	2 ²	–	10	–	
t_h	Hold time D_{sa} , D_{sb} to CP	Figure 3	1.2	–	–10	–	–	–	ns
			2.0	5	–3	–	5	–	
			2.7	5	–2	–	5	–	
			3.0 to 3.6	5	–2 ²	–	5	–	
			4.5 to 5.5	5	–1 ²	–	5	–	
f_{max}	Maximum clock pulse frequency	Figure 1	2.0	14	40	–	12	–	MHz
			2.7	19	58	–	16	–	
			3.0 to 3.6	24	70 ²	–	20	–	
			4.5 to 5.5	36	100 ²	–	30	–	

NOTE:

1. Unless otherwise stated, all typical values are at $T_{\text{amb}} = 25^\circ\text{C}$.
2. Typical value measured at $V_{\text{CC}} = 3.3\text{V}$.
3. Typical value measured at $V_{\text{CC}} = 5.0\text{V}$.

8-bit serial-in/parallel-out shift register

74LV164

AC WAVEFORMS

$V_M = 1.5V$ at $V_{CC} \geq 2.7V \leq 3.6V$
 $V_M = 0.5V * V_{CC}$ at $V_{CC} < 2.7V$ and $\geq 4.5V$
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

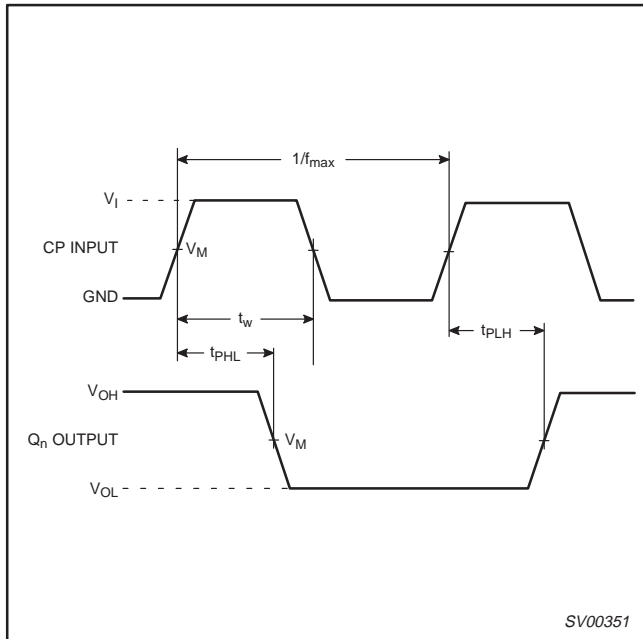


Figure 1. The clock (CP) to output (Q_n) propagation delays, the clock pulse width, the output transition times and the maximum clock pulse frequency

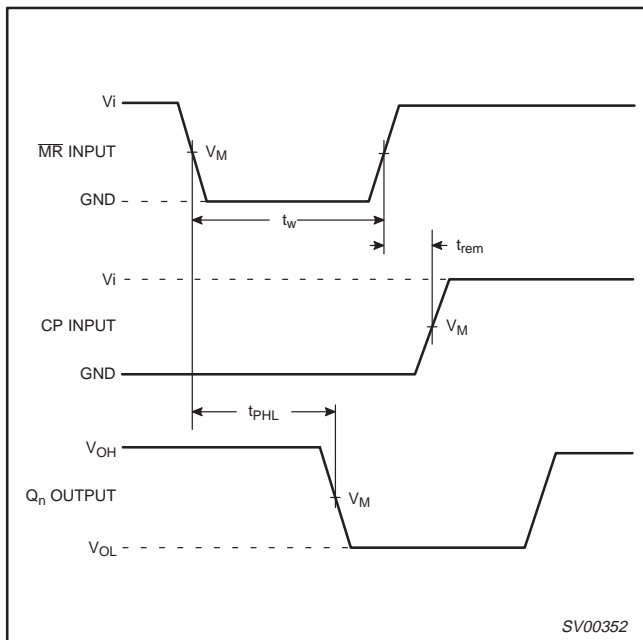


Figure 2. The master reset (\overline{MR}) pulse width, the master reset to output (Q_n) propagation delay and the master reset to clock (CP) removal time

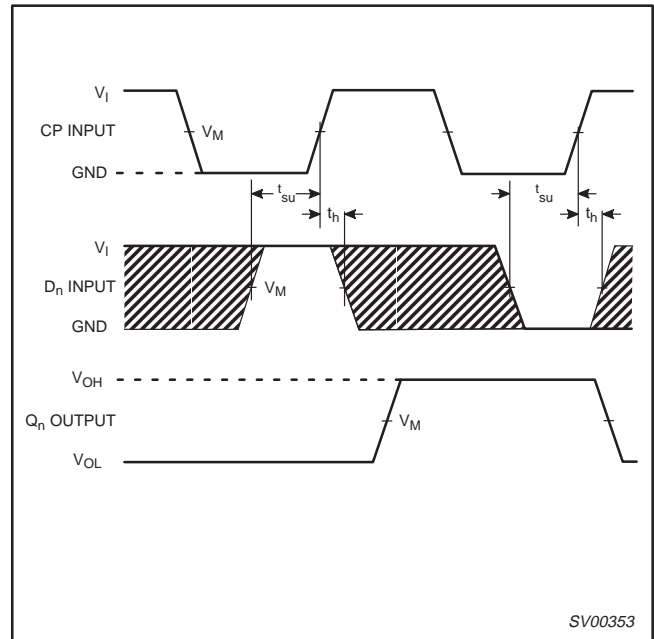


Figure 3. Data set-up and hold times for the D_n inputs

NOTE:

The shaded areas indicate when the input is permitted to change for predictable output performance.

TEST CIRCUIT

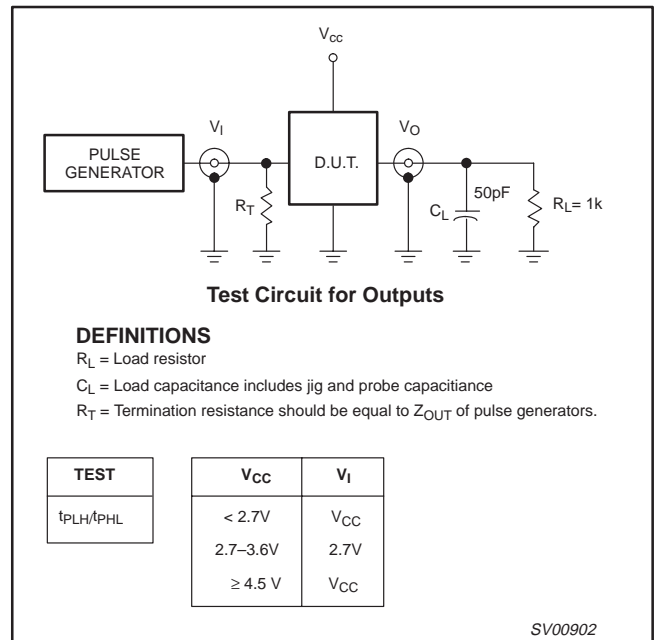


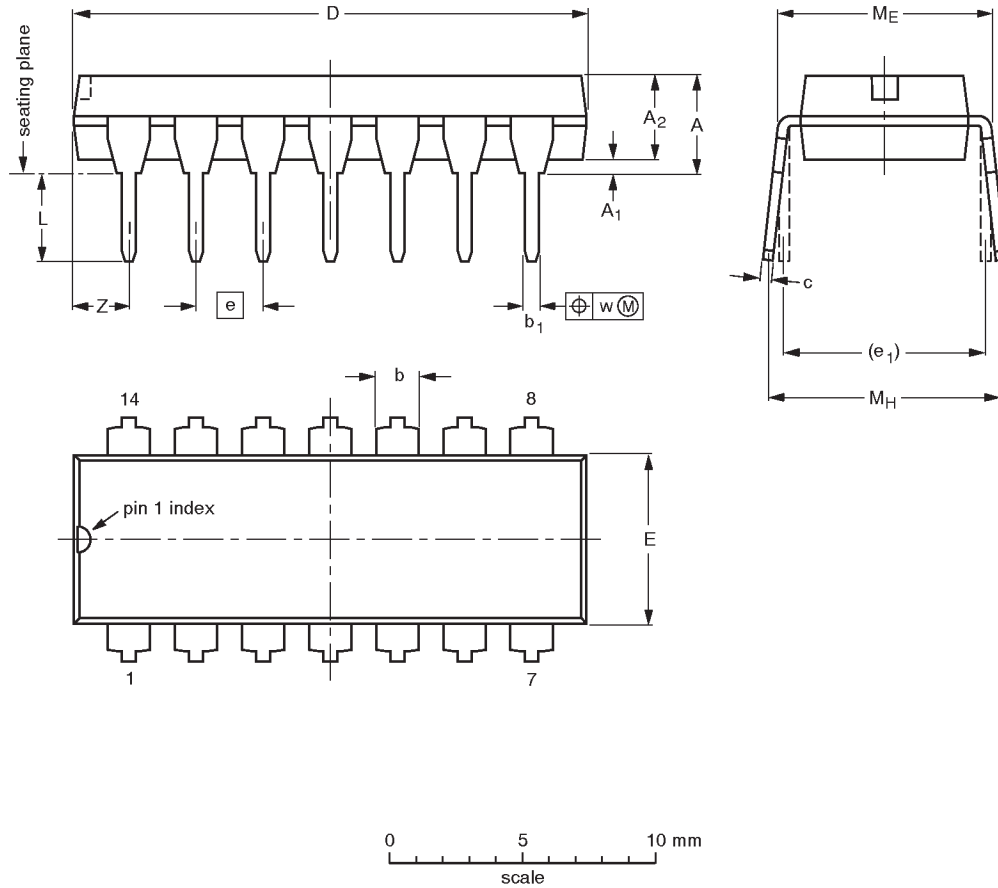
Figure 4. Load circuitry for switching times

8-bit serial-in/parallel-out shift register

74LV164

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

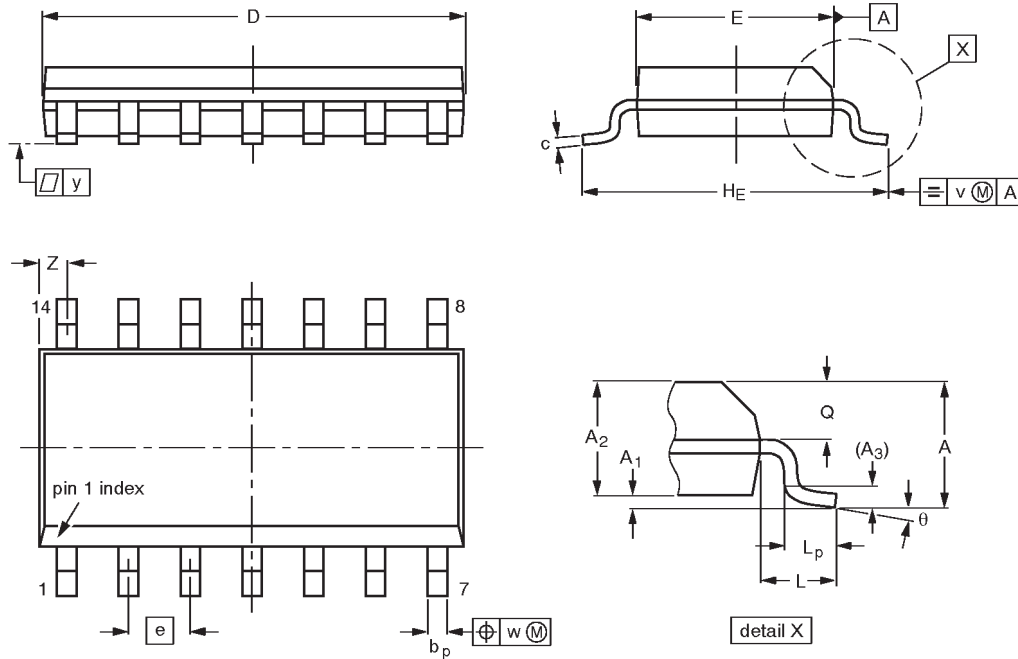
OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT27-1	050G04	MO-001AA			92-11-17 95-03-11

8-bit serial-in/parallel-out shift register

74LV164

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.0098 0.0039	0.057 0.049	0.01	0.019 0.014	0.0098 0.0075	0.35 0.34	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

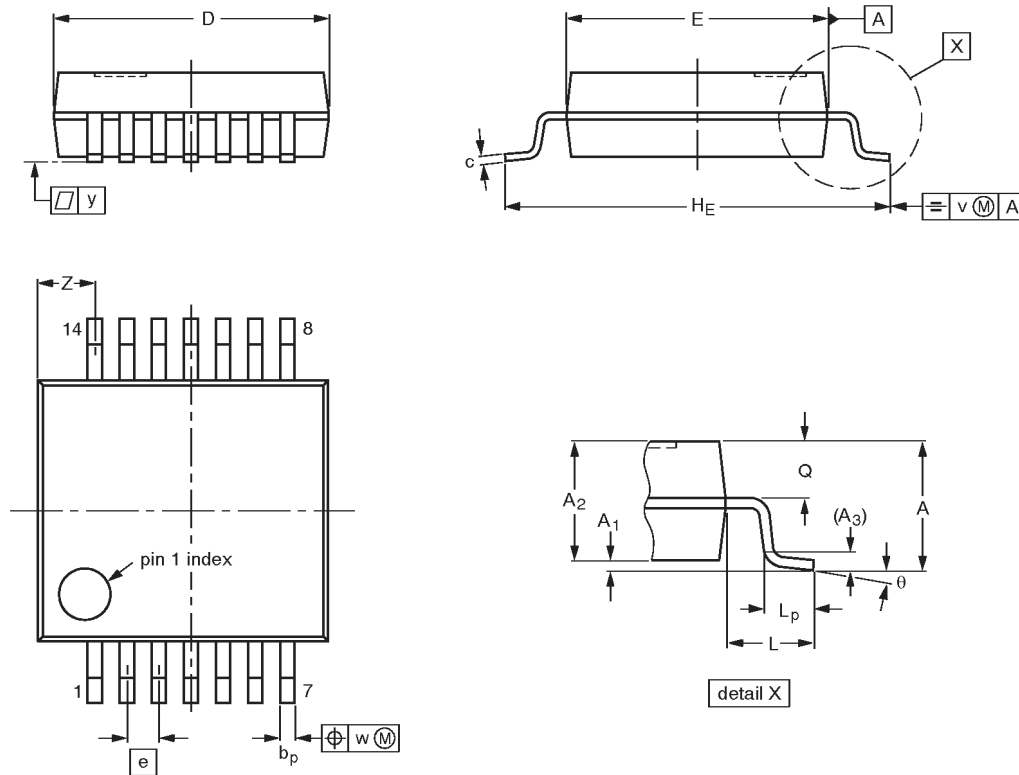
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT108-1	076E06S	MS-012AB				91-08-13 95-01-23

8-bit serial-in/parallel-out shift register

74LV164

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

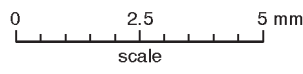
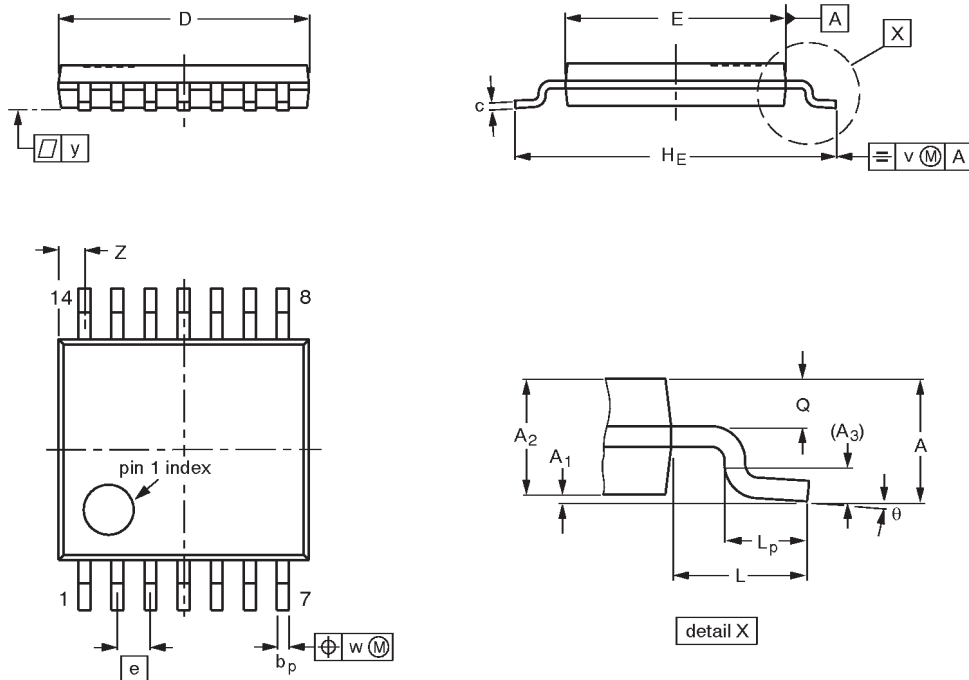
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT337-1		MO-150AB				95-02-04 96-01-18

8-bit serial-in/parallel-out shift register

74LV164

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT402-1		MO-153				-94-07-12- 95-04-04

8-bit serial-in/parallel-out shift register

74LV164

DEFINITIONS

Data Sheet Identification	Product Status	Definition
<i>Objective Specification</i>	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
<i>Preliminary Specification</i>	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
<i>Product Specification</i>	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

Philips Semiconductors and Philips Electronics North America Corporation reserve the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified. Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

LIFE SUPPORT APPLICATIONS

Philips Semiconductors and Philips Electronics North America Corporation Products are not designed for use in life support appliances, devices, or systems where malfunction of a Philips Semiconductors and Philips Electronics North America Corporation Product can reasonably be expected to result in a personal injury. Philips Semiconductors and Philips Electronics North America Corporation customers using or selling Philips Semiconductors and Philips Electronics North America Corporation Products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors and Philips Electronics North America Corporation for any damages resulting from such improper use or sale.

Philips Semiconductors
811 East Arques Avenue
P.O. Box 3409
Sunnyvale, California 94088-3409
Telephone 800-234-7381

© Copyright Philips Electronics North America Corporation 1998
 All rights reserved. Printed in U.S.A.

print code

Date of release: 05-96

Document order number:

9397-750-04431

Let's make things better.